

ROITHNER LASERTECHNIK GIRBH

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Rev. A2

PRELIMINARY

LED850D-66-16100

- Infrared High Power LED Array
- 850 nm, 8 W
- Chip: 1x1 mm, 16 pcs., AlGaAs
- TO-66 package, Silicone and/or Epoxy resin
- Viewing Angle: 126°





Description

LED850D-66-16100 is a wide viewing and extremely high output power illuminator consists of 16 pcs. 1x1 mm high current driven AlGaAs chip dies, mounted on a metal stem TO-66 package and covered with clear silicone and/or epoxy resin.

It is designed for wide viewing and extremely high output power illuminator.

On forward bias, it emits a power radiation of typical 8 W at a peak wavelength at 850 nm.

Maximum Ratings (TCASE=25°C)

Danamatan	Cymala al	Val	I Incid		
Parameter	Symbol	Min.	Max.	Unit	
Power Dissipation	P_D		40	W	
Forward Current	IF		4	Α	
Reverse Voltage	V_F		20	V	
Thermal Resistence	T_{thja}		2	K/W	
Junction Temperatur	T_J		120	°C	
Operating Temperature	TCASE	- 40	+ 85	°C	
Storage Temperature	T_{STG}	- 40	+ 100	°C	
Lead Solder Temperature *	T_{SLD}		+ 265	°C	

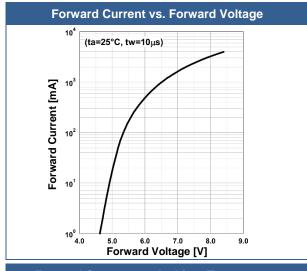
^{*} must be completed within 3 seconds

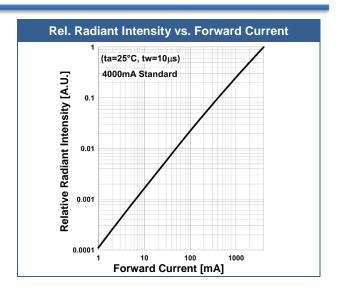
Electro-Optical Characteristics (TCASE=25°C)

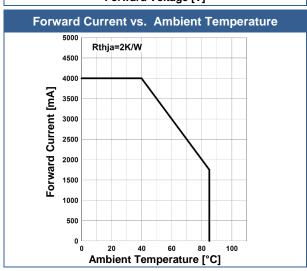
Parameter	Symbol	Conditions	Min.	Values Typ.	Max.	Unit
Peak Wavelength	λ_P	I _F =4.0A	840		865	nm
Half Width	$\Delta \lambda$	I _F =4.0A		37		nm
Forward Voltage	VF	$I_F=4.0A$		8.4	10	V
Radiated Power *	Po	I _F =4.0A		8.0		W
Viewing Angle	$\boldsymbol{\varphi}$	$I_F=100mA$		126		deg.
Rise Time	tr	I _F =4.0A		35		ns
Fall Time	tf	I _F =4.0A		20		ns

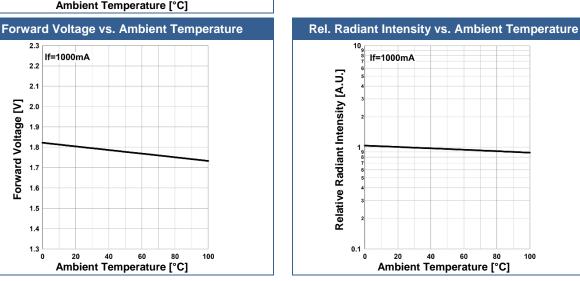
^{*} measured by \$3584-08

Typical Performance Curves







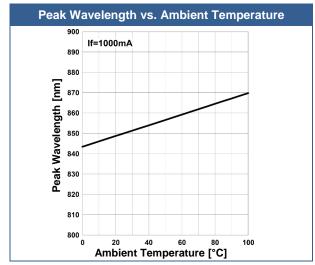


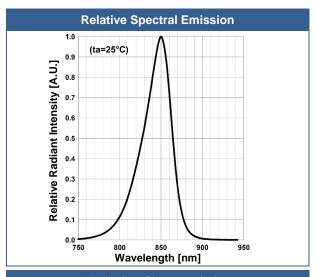


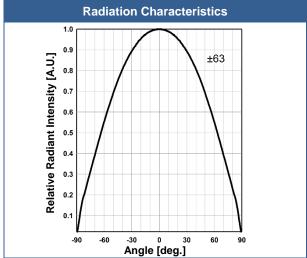
ROITHNER LASERTECHNIK GmbH

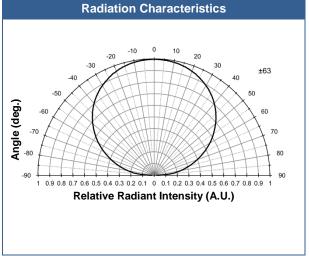
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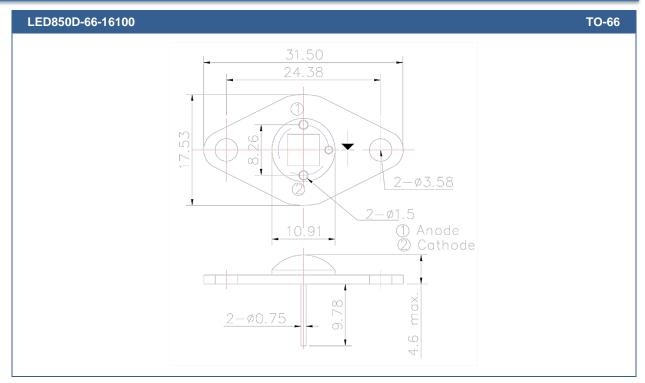








Outline Dimensions



All Dimensions in mm

Precautions

Cautions:

- This high power LED must be cooled!
- NOT look directly into the emitting area of the LED during operation!

Soldering:

- Do avoid overheating of the LED
- Do avoid electrostatic discharge (ESD)
- · Do avoid mechanical stress, shock, and vibration
- Do only use non-corrosive flux
- Do not apply current to the LED until it has cooled down to room temperature after soldering

Cleaning:

Cleaning with isopropyl alcohol, propanol, or ethyl alcohol is recommended

DO NOT USE acetone, chloroseen, trichloroethylene, or MKS

DO NOT USE ultrasonic cleaners

Static Electricity:

LEDs are sensitive to electrostatic discharge (ESD). Precautions against ESD must be taken when handling or operating these LEDs. Surge voltage or electrostatic discharge can result in complete failure of the device.

Radiation:

During operation these LEDs do emit **high intensity light**, which is hazardous to skin and eyes, and may cause cancer. Do avoid exposure to the emitted light. **Protective glasses are recommended**. It is further advised to attach a warning label on products/systems.

Operation:

Do only operate LEDs with a current source.

Running these LEDs from a voltage source will result in complete failure of the device.

Current of a LED is an exponential function of the voltage across it. Usage of current regulated drive circuits is mandatory.

Revisions History

Rev.	Rel. Date	Chapter	Modification	Page
A2	2018-05-18	Electro-Optical Characteristics	Po: 8 W (previously 2.8 W)	1
		Typical Performance Curves	Revised	2-3
		Revisions History	Included	6
A1	2018-04-05	-	Initial release	-

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